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Ishida

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(54) **APPARATUS AND METHOD FOR WARPAGE
COMPENSATION OF A DISPLAY PANEL
SUBSTRATE ASSEMBLY**

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patent is extended or adjusted under 35
U.S.C. 154(b) by 81 days.

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Related U.S. Application Data

(60) Provisional application No. 60/369,958, filed on Apr. 4,
2002.

(51) **Int. Cl.**⁷ **H01J 1/62**

(52) **U.S. Cl.** **313/512; 313/504; 313/505**

(58) **Field of Search** 313/500, 504,
313/505, 511, 512; 362/84, 249; 427/66;
438/51; 257/59; 315/169.3

(56) **References Cited**

U.S. PATENT DOCUMENTS

6,642,652 B2 * 11/2003 Collins, III et al. 313/512

* cited by examiner

Primary Examiner—Vip Patel

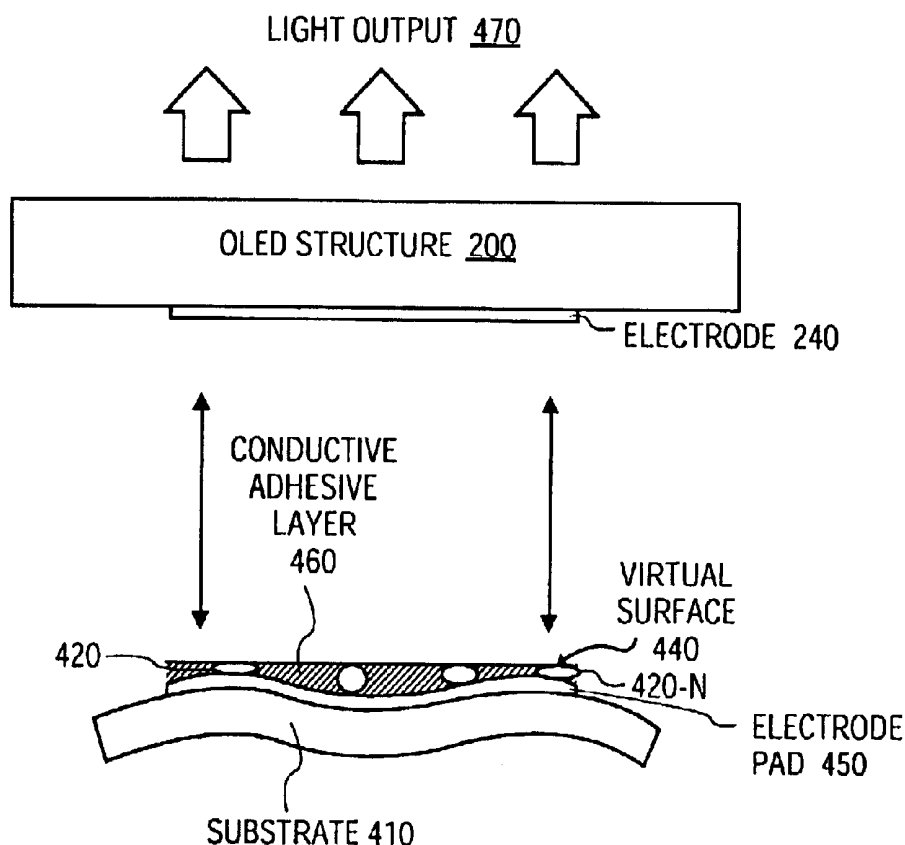
Assistant Examiner—Glenn Zimmerman

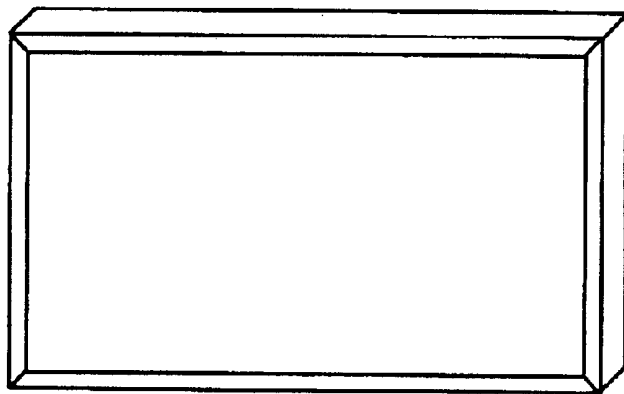
(74) *Attorney, Agent, or Firm*—Blakely, Sokoloff, Taylor &
Zafman LLP

(57) **ABSTRACT**

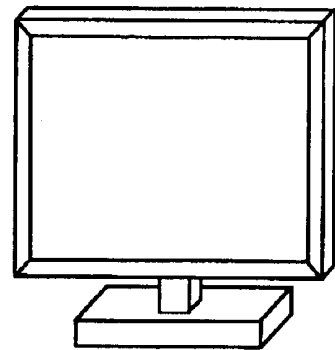
An apparatus and method for warpage compensation of a display panel substrate assembly are described. A method and apparatus for warpage compensation of a display panel substrate assembly are described. In one embodiment, the method includes the selection of a substrate having a substrate warpage level exceeding a warpage tolerance level. Once selected, a plurality of conductive bumps are formed over an area of the selected substrate. Once formed, a thermal process is applied to the plurality of conductive bumps to obtain a virtual plane over the area of the selected substrate have a coplanarity level below a coplanarity specification level. As such, utilizing embodiments of the present invention, lower cost substrates with substandard warpage levels may be utilized to form OLED panel substrate assemblies when compensated utilizing embodiments of the present invention.

10 Claims, 8 Drawing Sheets



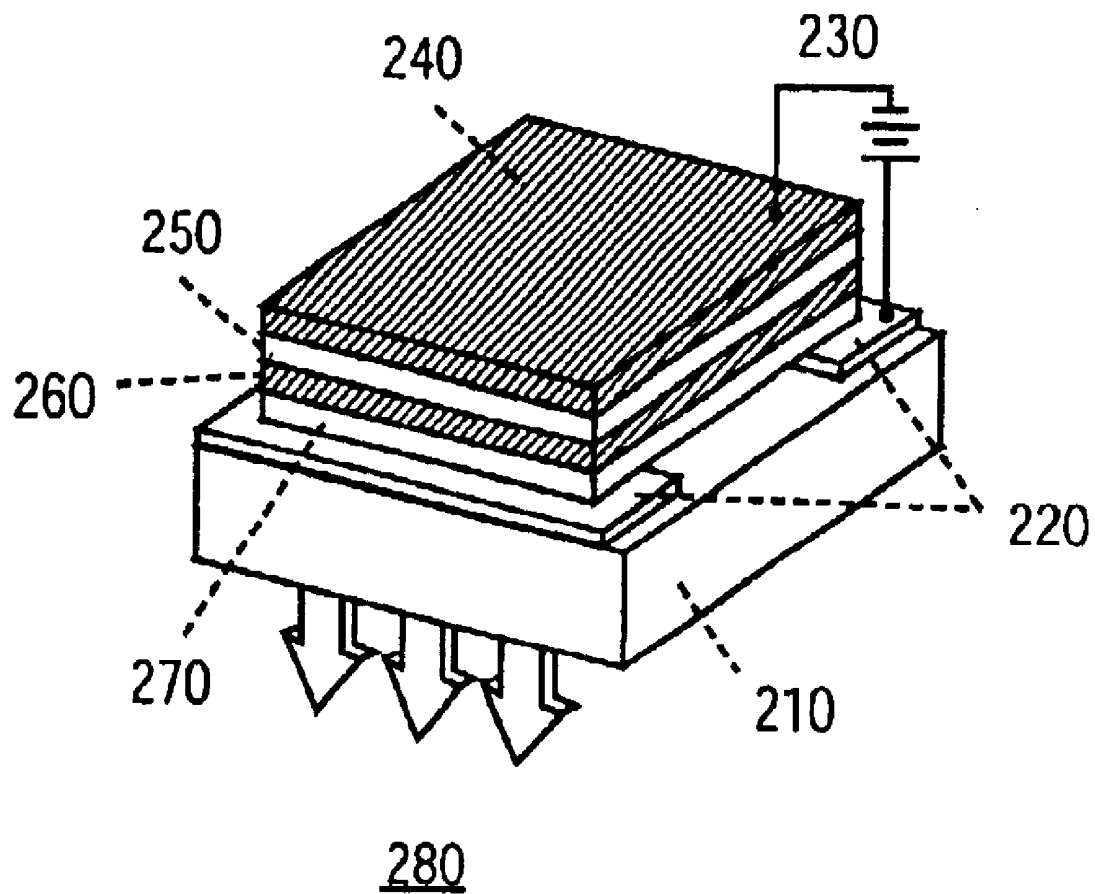


FLAT-SCREEN TV 100



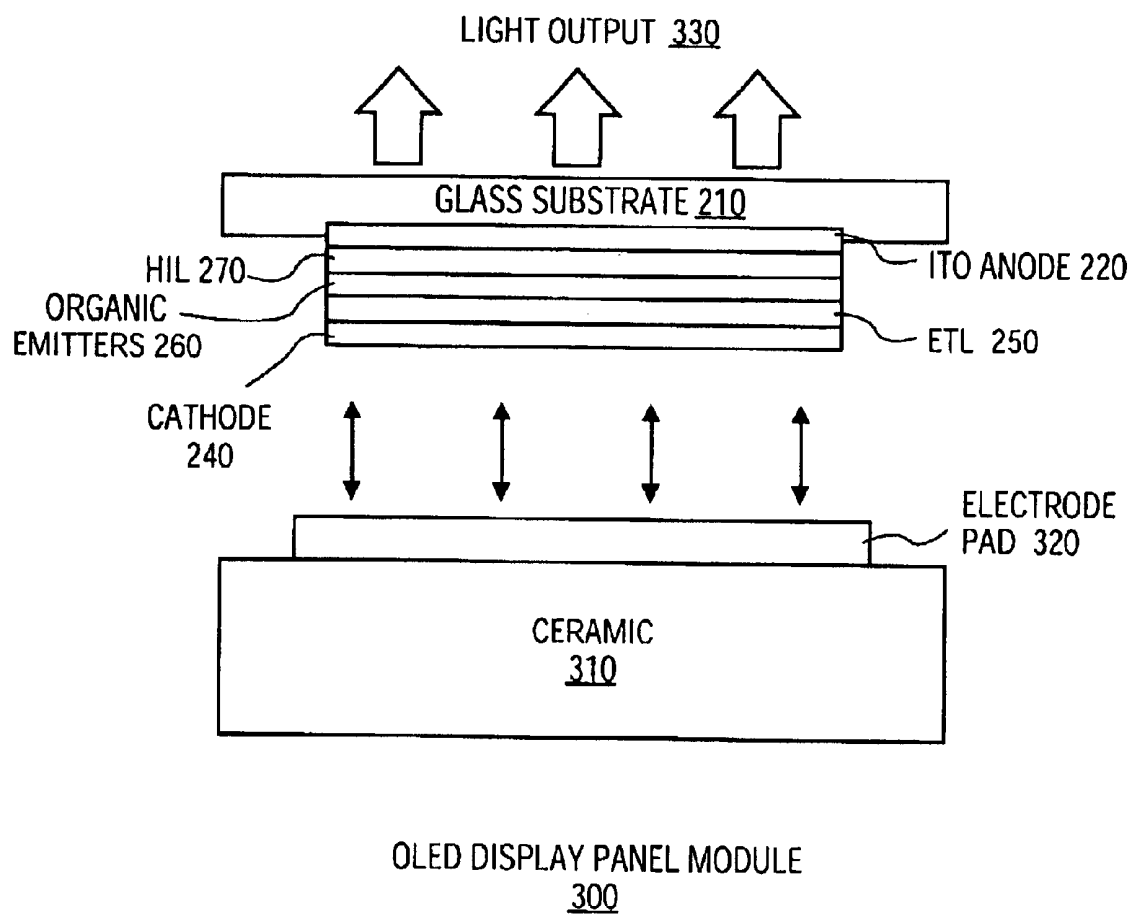
FLAT-SCREEN MONITOR
110

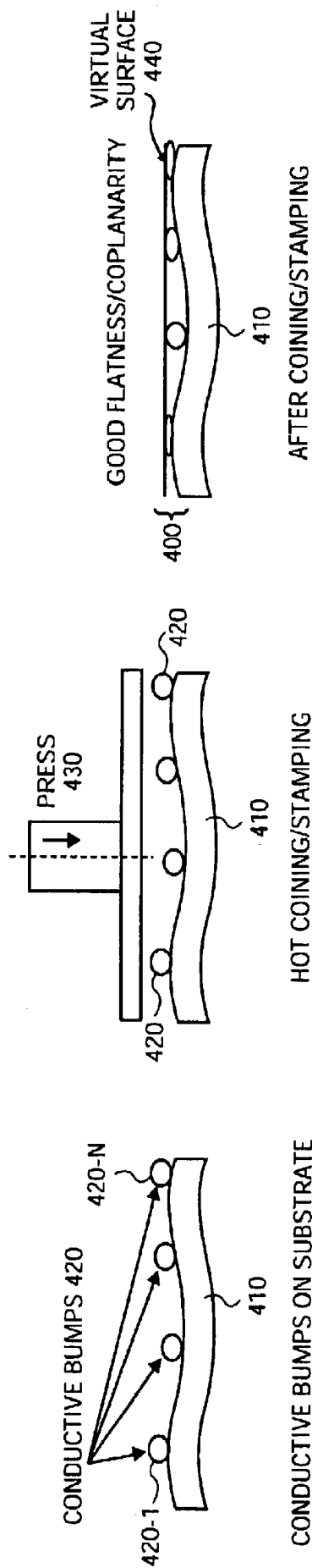
FIG. 1



OLED STRUCTURE 200

FIG. 2

**FIG. 3**

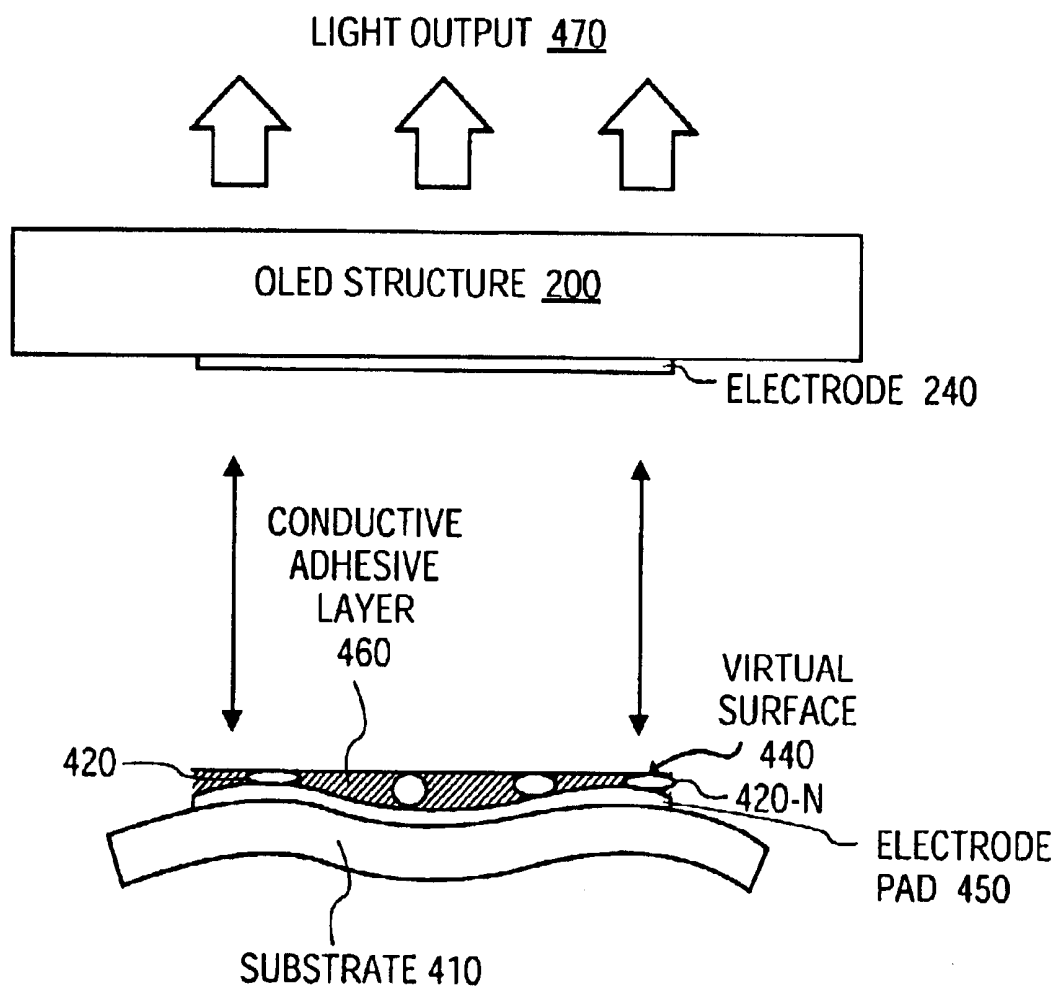


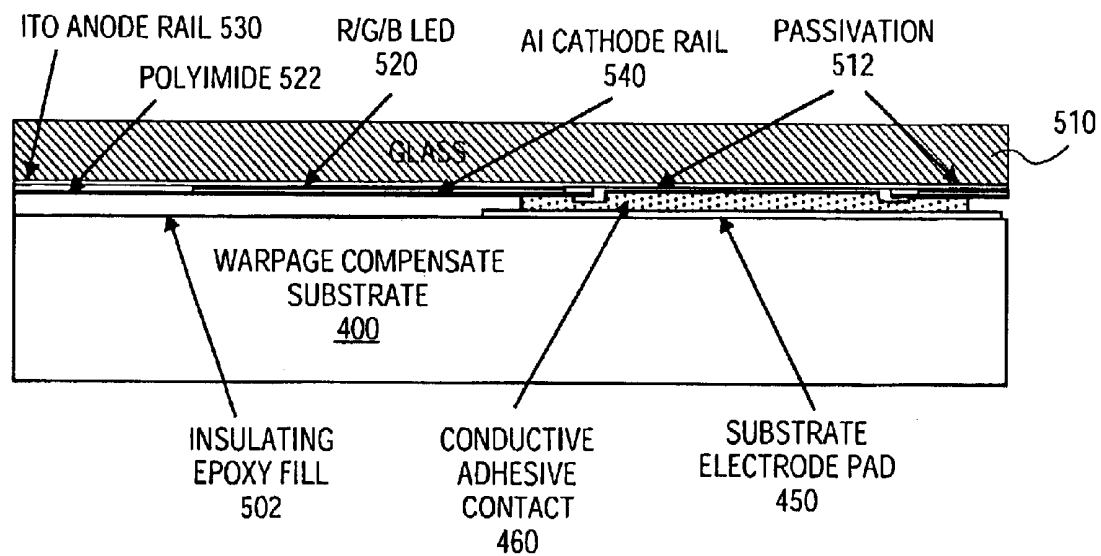
WARPAGE COMPENSATED SUBSTRATE 400

FIG. 4A

FIG. 4B

FIG. 4C

**FIG. 5**

OLED DISPLAY PANEL MODULE 500**FIG. 6**

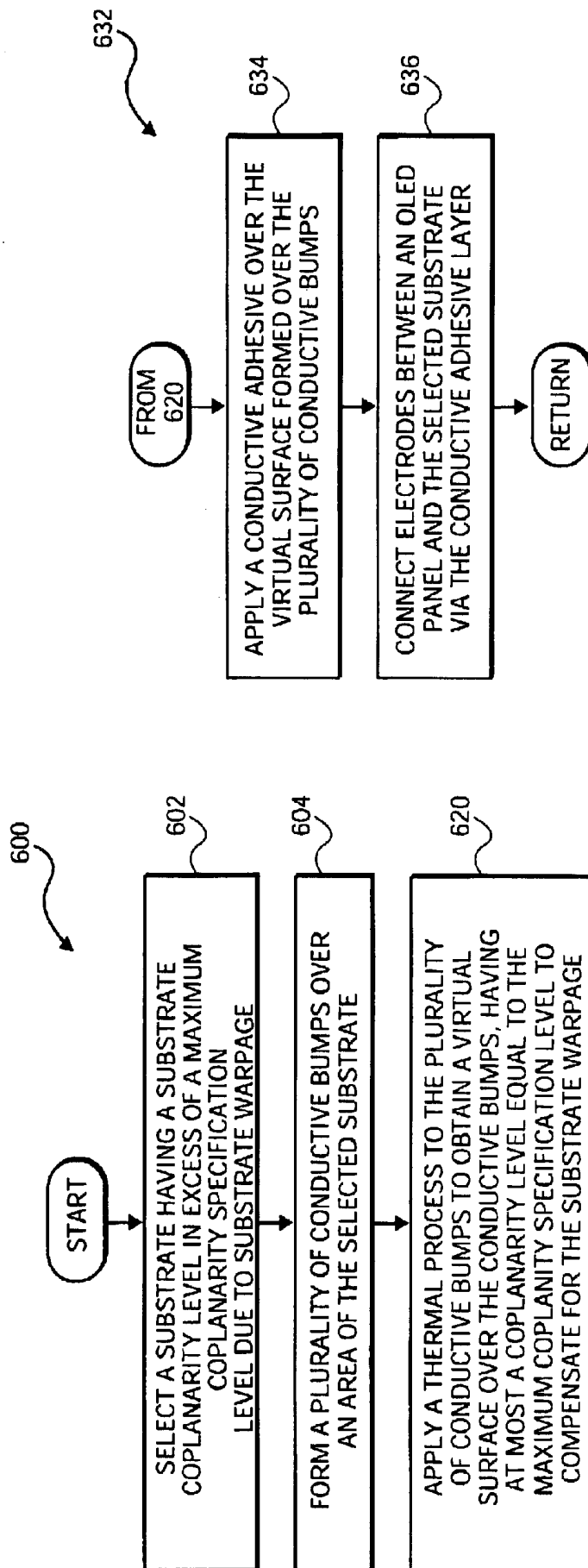


FIG. 8

FIG. 7

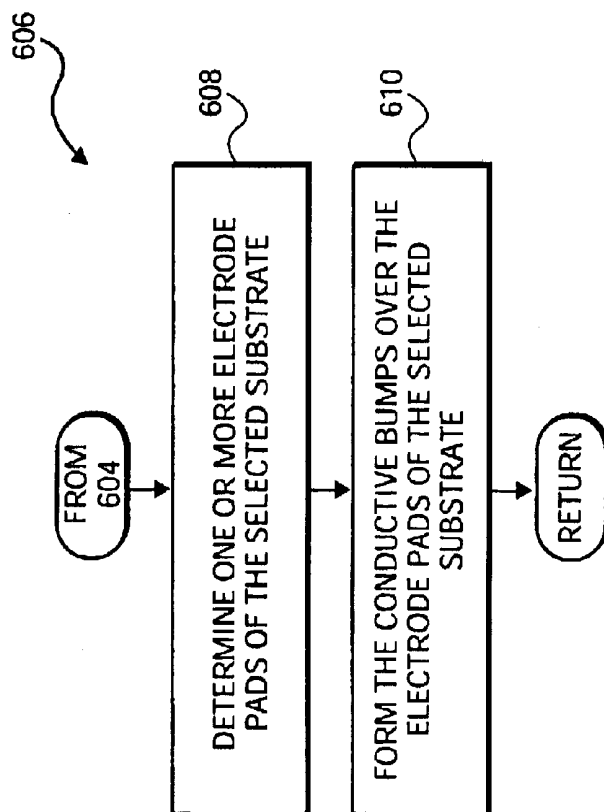


FIG. 9

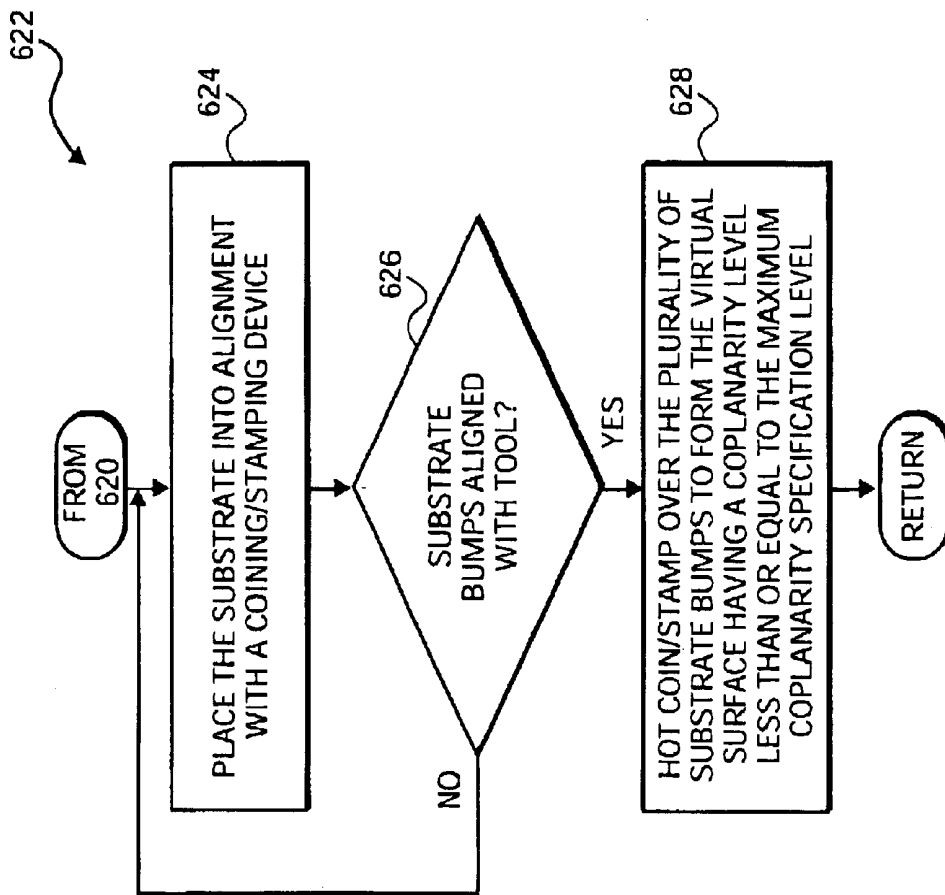


FIG. 10

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APPARATUS AND METHOD FOR WARPAGE COMPENSATION OF A DISPLAY PANEL SUBSTRATE ASSEMBLY

RELATED APPLICATION

This application is a non-provisional application based upon U.S. Provisional Application Ser. No. 60/369,958, filed on Apr. 4, 2002, now expired.

FIELD

One or more embodiments relate generally to the field of organic light-emitting diode (OLED) displays. More particularly, one or more of the embodiments relates to a method and apparatus for warpage compensation of a display panel substrate assembly.

BACKGROUND

Traditional liquid crystal displays (LCDs) are utilized as conventional display devices. Unfortunately, LCDs require backlighting, as well as diffusers and polarizers, since LCD displays are not self-luminous. Furthermore, the backlighting is generally provided by bulky and environmentally undesirable mercury lamps, which consume inordinate amounts of power. Likewise, the lumination within LCDs often generates undesirable amounts of heat and causes electrical interference within attached electronic devices. As a result, LCDs generally require substantial space and are often quite heavy.

In contrast, organic light-emitting diode (OLED) technology generally enables full color, full motion, flat panel displays, with a level of brightness and sharpness not possible with traditional LCDs. Moreover, unlike traditional LCDs, OLEDs are self-luminous. As a result, flat panel displays utilizing OLEDs do not incur many of the problems suffered by traditional LCDs.

An OLED structure, which is utilized to enable an OLED display device generally includes organic carbon-based film layers between two charged electrodes. A first electrode is commonly a metallic or conductive cathode, while a second electrode is commonly a transparent anode, generally made of glass. The organic film layers may comprise a hole injection layer, a hole transport layer, an emissive layer and an electron transport layer.

In operation, a voltage potential is applied to an OLED structure to provide rumination within the OLED display device. When the charge is applied, the injected positive and negative charges within the OLED recombine in an emissive layer in order to create electroluminescent light. As a result, OLED displays emit light, in contrast with conventional display technologies, such as LCD displays, which modulate transmitted or a reflected light.

An OLED structure may also include a ceramic panel and a conductive adhesive contact. In order to construct panels, such as OLED displays, some kind of substrate, such as a ceramic, organic or metallic plate, is required. As such, the substrate enables assembly of an OLED panel that is constructed of glass or organic film in order to enable connection to an electric circuit. However, in order to enable full motion flat panel displays, a warpage tolerance/coplanarity specification value required of selected substrates is generally less than 30 microns per inch (micron/inch).

Unfortunately, the coplanarity specification required for OLED flat panel displays drastically increases the cost to manufacturers of OLED displays. In order to address the warpage tolerance coplanarity specification requirements,

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manufacturers of conventional OLED displays generally utilize higher cost ceramic substrates. Otherwise, the manufacturers utilize special treatments (polishing), which are applied to ceramic substrates to reduce the warpage level of the substrate to conform to required tolerances. Consequently, conventional processes for enabling flat panel OLED display construction significantly increase the costs of substrate material.

BRIEF DESCRIPTION OF THE DRAWINGS

The various embodiments are illustrated by way of example, and not by way of limitation, in the figures of the accompanying drawings and in which:

FIG. 1 depicts block diagrams illustrating a flat screen television (TV), as well as a flat screen monitor.

FIG. 2 depicts a block diagram illustrating an optical light emitting diode (OLED) structure.

FIG. 3 depicts a block diagram illustrating an OLED display panel module.

FIGS. 4A-4C depict block diagrams illustrating warpage compensation of a substrate.

FIG. 5 depicts a block diagram illustrating formation of an OLED display panel module utilizing a warpage compensated substrate.

FIG. 6 depicts a block diagram illustrating an OLED display panel module.

FIG. 7 depicts a flowchart illustrating a method for performing warpage compensation of a selected substrate to enable usage of the substrate within an OLED display panel module assembly.

FIG. 8 depicts a block diagram illustrating a method for coupling an OLED panel to a warpage compensated substrate.

FIG. 9 depicts a flowchart illustrating a method for forming a plurality of conductive bumps over an area of a selected substrate.

FIG. 10 depicts a flowchart illustrating an additional method for applying a thermal process to the plurality of conductive bumps to obtain a virtual surface.

DETAILED DESCRIPTION

A method and apparatus for warpage compensation of a display panel substrate assembly are described. In one embodiment, the method includes the selection of a substrate having a substrate warpage level exceeding a warpage tolerance level. Once selected, a plurality of conductive bumps are formed over an area of the selected substrate. Once the conductive bumps are formed, a thermal process is applied to the plurality of conductive bumps to obtain a virtual surface over the area of the selected substrate have a maximum coplanarity level below a coplanarity specification level.

In one embodiment, the apparatus includes a substrate including a plurality of conductive bumps having a virtual plane with a coplanarity level below the maximum coplanarity specification level. The virtual surface is formed by applying a thermal process to the plurality of conductive bumps. An adhesive conductive layer formed over the virtual surface. In addition, the apparatus includes an OLED panel layer coupled to the substrate via the adhesive conductive layer to connect electrodes between the OLED panel and the substrate. As such, utilizing embodiments of the present invention, lower cost substrates with substandard warpage levels may be utilized to form OLED panel sub-

strate assemblies when compensated utilizing embodiments of the present invention.

In the following description, for the purposes of explanation, numerous specific details are set forth in order to provide a thorough understanding of the embodiments of the present invention. It will be apparent, however, to one skilled in the art that the various embodiments of the present invention may be practiced without some of these specific details. For example, various substrates and conductive bump configurations may be modified according to the embodiments of the present invention to provide the desired virtual surface coplanarity level.

In addition, the following description provides examples, and the accompanying drawings show various examples for the purposes of illustration. However, these examples should not be construed in a limiting sense as they are merely intended to provide examples of the embodiments of the present invention rather than to provide an exhaustive list of all possible implementations of the embodiments of the present invention. In other instances, well-known structures and devices are shown in block diagram form in order to avoid obscuring the details of the various embodiments of the present invention.

FIG. 1 depicts block diagrams illustrating flat screen TV 100, as well as flat screen monitor 110. In contrast to conventional televisions, as well as computer monitors, flat screen TV 100 and flat screen monitor 110 are drastically smaller than conventional televisions and monitors. However, flat screen TV 100, as well as flat screen monitor 110, include a screen size, which is as large, if not larger, than a corresponding contemporary devices. Flat screen devices depicted in FIG. 1 have become a reality due to the use of, for example, optical light emitting diodes (OLED).

As indicated above, traditional liquid crystal displays (LCDs) are generally not self-luminous. As a result, back-lighting is required to illuminate the displays, which is provided by bulky environmentally undesirable mercury lamps, which consume an inordinate amount of power. As a result, LCDs generally require substantial space, and are often quite heavy in contrast to the flat panel displays depicted in FIG. 1. In contrast, organic light emitting diode technology enables full color, full motion, flat panel displays with a level of brightness and sharpness that is not possible with traditional LCDs. Moreover, unlike traditional LCDs, OLEDs are self-luminous. As a result, flat panel display modules constructed utilizing OLEDs do not incur many of the problems suffered by traditional LCDs.

FIG. 2 depicts OLED structure 200, which may be utilized within flat panel displays, as depicted in FIG. 1. OLED structure 200 generally includes organic carbon-based film layers between two charged electrodes. For example, OLED structure 200 includes glass substrate 210, including, for example, transparent anode 220, generally made of glass or indium-tin oxide (ITO). The organic layers comprise a hole injection layer (HIL) 270, organic emitters 260, as well as electron transport layer (ETL) 250. Likewise, OLED structure 200 includes metal cathode 240 above organic film layers (250, 260 and 270).

In operation, voltage potential 230 is applied to OLED structure 200 in order to provide lumination within an OLED display device utilizing OLED structure 200. When the charge is applied, the injected positive and negative charges within OLED structure 200 recombine in an emissive layer in order to create electroluminescent light. As a result, OLED displays emit light, in contrast with conventional display technology, such as LCD displays, which

modulate transmitted or reflected light. As such, when voltage potential 230 of, for example, two ten volts direct current is applied to metal cathode 240 and anode 220, light output 280 is generated from OLED structure 200.

Conventionally, OLED structure 200 may be utilized to form an OLED display module, for example, as depicted in FIG. 3. As illustrated in FIG. 3, OLED display panel module 300 is formed utilizing OLED structure 200, for example, as depicted in FIG. 2. In order to construct OLED display panel module 300, as depicted in FIG. 3, some kind of substrate 310, such as a ceramic, organic or metallic plate is required.

As such, substrate 310 enables assembly of an OLED panel that is constructed of a glass organic film in order to enable connection to an electric circuit, for example, to provide a voltage potential between cathode 240 and anode 220, to generate lumination from glass structure 210. However, in order to meet the strict tolerances required to manufacture flat panel displays, for example, as depicted in FIG. 1, a warpage tolerance/coplanarity specification value required of selected substrates, for example, substrate 310, is generally less than 30 microns per inch.

Unfortunately, the coplanarity specification level required for OLED flat panel displays drastically increases the cost to manufacture OLED displays, such as flat panel TVs, as well as flat panel screen 100, as depicted in FIG. 1. In order to address the warpage tolerance/coplanarity specification requirements, manufacturers of conventional OLED displays generally utilize higher cost ceramic substrates having a coplanarity level, which is at most equal to the 30 micron per inch coplanarity specification value required for OLED display devices. Otherwise, the manufacturers utilize special treatments, such as polishing, which are applied to ceramic substrates in order to remove warpage from the substrates such that the final substrate includes a coplanarity value, which is less than the 30 microns per inch coplanarity specification requirement.

As a result of the warpage tolerance/coplanarity specification requirements for substrates utilized within OLED display panel modules, flat screen TVs, as well as monitors, utilizing OLED display panel modules are often quite expensive. As indicated, substantial costs are further exacerbated by finding substrates which comply with the coplanarity specification requirements. However, in order to combat the coplanarity specification requirements for OLED display panel modules, FIGS. 4A-4E illustrate an embodiment for performing warpage compensation of a substrate to enable usage of the substrate within an OLED display panel module assembly.

FIG. 4A depicts substrate 410, which has an undesirable warpage level, which may be in the range of 60 microns per inch through 700 microns per inch. Conventional coplanarity specification requirements are generally, at most, 30 microns per inch, which is quite uncommon in substrate materials used widely in the semiconductor industry. Such substrate material includes, for example, alumina ceramic, low temperature co-fired ceramic and other various ceramics, as well as printed circuit boards utilizing organic (plastic) substrate materials. Accordingly, the OLED display industry is now trying to adopt a standard of using only ceramic substrates, as well as adding special treatment, to reduce the warpage level down to within half of the industry specification.

Unfortunately, adoption of the standard proposed by the manufacturers of flat screen devices will significantly increase substrate cost. In addition, substrate development work will also be required. Consequently, in order to comply

with the coplanarity specification requirements for substrates utilized within OLED displays, one embodiment includes a process for compensation of substrate warpage, for example, as depicted in FIGS. 4A–4C.

Referring now to FIG. 4A, substrate **410** is selected, which has an undesirably high warpage level. As a result, a substrate coplanarity level of the surface of substrate **410** generally exceeds the maximum coplanarity specification value of, for example, 30 microns per inch. Therefore, in accordance with one embodiment, conductive bumps **420** are formed upon an area of substrate **410**. In one embodiment, conductive bumps **420** may be formed onto electrode pads of substrate **410** (not shown).

In one embodiment, the conductive bumps **420** are generally configured as soft bumps, which require electrical conductivity, as well as deformation characteristics at a certain temperature. In one embodiment, the conductive bumps may have a diameter within the range of 50 μm to 300 μm depending on the desired resolution. In one embodiment, the electrode pads are comprised of a material including ITO, Aluminum pad with gold flash plating, or electric pads with Ni/Au plating or Sn plating.

Accordingly, the soft bumps may be comprised of a material including various metals, such as solder bumps, as well as conductive plastic-elastic materials, such as, but not limited to Pb/Sn alloy Au, conductive rubber, and the like. Once conductive bumps **420** are formed upon substrate **410**, hot coining/stamping tool **430** may be applied to conductive bumps **420**. As such, in embodiment depicted in FIG. 4B, a hot coining/stamping tool **430** is applied to conductive bumps **420**. Once applied, hot coining/stamping tool **430** will cause the formation of a virtual plane (surface) **440** over the soft bumps, for example, as depicted in FIG. 4C. In general, a tool with up/down stroke motion with some dead weight control may be used as tool **430**. Precise alignment is generally not required, since bump coining is performed for a desired area.

In the embodiments depicted, the virtual surface **440** will have a coplanarity level, which at most is equal to the coplanarity specification requirement value of, for example, 30 microns per inch. Accordingly, after coining/stamping conductive bumps **420**, virtual surface **440** is formed, which has an acceptable coplanarity level. As such, virtual surface **440** enables the formation of warpage compensated substrate **400**, as depicted in FIG. 4C. Consequently, utilizing the warpage compensated substrate, an OLED display panel module assembly may be formed utilizing a substrate, which initially fails to meet the coplanarity specification requirement.

FIG. 5 depicts the formation of an OLED display panel module assembly utilizing warpage compensated substrate **400** of FIG. 4. As illustrated, OLED structure **200**, for example, as depicted in FIG. 2, will include electrode **240**. Electrode **240** generally requires a current source to generate light output **470**. As such, in accordance with one embodiment, a conductive adhesive layer **460** of, for example, Pb/Sn conductive layer, is formed onto the virtual surface **440** and over electrode pad **450**.

Consequently, utilizing conductive adhesive layer **460**, an electronic connection is formed between electrode pad **450** and OLED electrode **240** to enable application of a voltage potential between substrate **410** and OLED structure **200** to generate light output **470**. As such, an OLED display panel module assembly is generated in accordance with the embodiment depicted in FIG. 5 to generate light output **470** and may be used to form a flat panel display television or screen, for example as depicted in FIG. 1.

FIG. 6 depicts OLED display panel module **500** formed utilizing warpage compensated substrate **400**, in accordance with a further embodiment. As illustrated, the OLED display panel module **500** includes warpage compensated substrate **400** having substrate electrode pads **450** and adhesive contact **460**. The adhesive contact **460** enables electronic connection between the electrodes **450** and (red/blue/green (R/G/B)) LED **520**. The OLED includes glass substrate **510**, including an indium-tin oxide (ITO) anode rail **530**, as well as aluminum (Al) cathode rail **540**, as well as passivation layer **512**. In one embodiment, the passivation overlies cathode rail **540** and protective layer **522** of, for example, silicon dioxide (SiO_2) polyamide disposed between a passivation layer **512** and warpage compensation substrate **400**.

In addition, conductive adhesive contact **560** is utilized to provide an electronic connection between substrate electrode pad **450** and Al cathode rail **540** to provide a voltage potential to LED **520**. As such, in accordance with one embodiment, an OLED display panel module assembly **500** is generated with red LED **520**, green LED **520**, as well as blue LED **520** to form an OLED display panel cell. As such, utilizing any combination of red, blue or green, a plurality of OLED display panel cells may be formed within a flat panel display device to generate a desired image.

Accordingly, utilizing embodiments described herein, an OLED display panel module assembly **500** may be formed utilizing conventional substrates, which have substandard warpage levels. Therefore, by compensating warpage levels of various substrates, an OLED display panel module assembly, as well as an OLED display panel cells are formed at a lower cost than conventional means. Consequently, flat panel display screen, may be manufactured at drastically lowered costs by utilizing OLED display panel module assemblies described according to embodiments of the present invention.

Operation

FIG. 7 depicts a flowchart illustrating method **600** for warpage compensation of substrate in order to enable usage of a substrate within an OLED display panel module assembly in accordance with one embodiment. Accordingly, at process block **602**, a substrate is selected having a coplanarity level in excess of a maximum coplanarity specification level due to warpage of the substrate. As indicated above, substrates traditionally used within the semiconductor industry, such as alumina ceramic, low temperature co-fired ceramic and other various ceramics, as well as printed circuit boards utilizing organic/(plastic) substrate materials. These substrates generally exhibit significant warpage levels, which may be in the range of 60 micrometers per inch through 700 micrometers per inch.

Once the substrate is selected, a plurality of conductive bumps are formed over an area of the substrate, at process block **604**. In one embodiment, the conductive bumps are comprised of a material, which includes electric conductivity as well as deformation characteristics at certain temperatures. In one embodiment, solder bumps (e.g., lead-tin solder bumps) may be utilized; however, the conductive bumps include, but are not limited to, conductive, plastic-elastic materials, such as synthetic polymers (plastics) including rubber, or the like. Finally, at process block **620**, a thermal process is applied to the plurality of conductive bumps to obtain a virtual surface over the conductive bumps, having at most a coplanarity level equal to the maximum coplanarity specification level to thereby compensate for warpage of the selected substrate.

FIG. 8 depicts a flowchart illustrating an additional method **632** for forming of an OLED display panel module

assembly utilizing the warpage compensated substrate, formed in accordance with method 600, as depicted in FIG. 7. At process block 634, a conductive adhesive is applied as a planar layer over the virtual surface of the plurality of conductive bumps. Once applied, electrodes between an OLED panel and the selected substrate are connected via the conductive adhesive material, using, for example, screen printing onto glass substrate 510 to provide the connection. For example, as depicted with reference to FIG. 5, OLED electrode 240 is connected with electrode pad 450 via conductive adhesive layer 460. Once such connection is formed, the substrate may apply a voltage potential via electrode pad 450 to electrode 240 in order to generate light output 470 via OLED structure 200.

FIG. 9 depicts a flowchart illustrating an additional method 606 for forming the conductive bumps of process block 604, as depicted in FIG. 7. At process block 608, one or more electrode pads of the selected substrate are determined. Once determined, at process block 610, the conductive bumps are formed over the electrode pads of the selected substrate. In one embodiment, the conductive bumps may be comprised of any material which provides electrical conductivity, as well as containing a deformation characteristic at a certain temperature. Accordingly, the soft bumps may be made of any metal, such as for example, solder, as well as conductive plastic-elastic materials, such as synthetic polymers (plastics), including, but not limited to, rubber. In one embodiment, when the conductive bumps are comprised of solder, the connection between the OLED electrode and the substrate electrode pads may be performed via solder joint interconnection.

FIG. 10 depicts a flowchart illustrating an additional method 622 for applying the thermal process of process block 620, as depicted in FIG. 7 and in accordance with the further embodiment of the present invention. As such, at process block 624, the substrate is placed into alignment within a coining/stamping device. Next, at process block 626, it is determined whether the substrate bumps are aligned with the tool. Once aligned, at process block 628, hot coining/stamping is performed over the plurality of conductive bumps to form the virtual surface, for example, as depicted in FIGS. 4B and 4C.

Accordingly, the virtual surface will have a nearly perfect coplanarity level and certainly a coplanarity level, which is at most, equal to the maximum coplanarity specification level. As such, by using hot coining or stamping over the conductive bumps, the coplanarity of the formed virtual surface compensates for the warpage of the selected substrate. Accordingly, utilizing embodiments of the present invention, conventional substrate materials may be utilized within OLED display panel modules without having to undergo special treatments to the selected substrate to compensate for the warpage or spending significant capital for ceramics which comply with coplanarity specification value requirements.

Consequently, utilizing embodiments of the present invention, OLED display panel modules assembly may be formed at drastically lower costs. As such, OLED display panel cells of R/G/B LEDs display panel modules assemblies may be utilized to form flat panel displays with full color and full motion, including a level of brightness and sharpness not possible with traditional devices. Likewise, interconnection systems for OLED display devices may select from a vast variety of substrate materials, including for example, thin film substrates to utilize within the OLED display panel module assembly process.

Alternate Embodiments

Several aspects of one implementation of the OLED display panel module assembly utilizing a warpage compensated substrate have been described. However, various implementations of the warpage compensation provide numerous features including, complementing, supplementing, and/or replacing the features described above. Features can be implemented as part of any assembly having strict coplanarity requirements in different embodiment implementations. In addition, the foregoing description, for purposes of explanation, used specific nomenclature to provide a thorough understanding of the embodiments presented. However, it will be apparent to one skilled in the art that the specific details are not required in order to practice the embodiments.

In addition, although an embodiment described herein is directed to a OLED display panel module assembly, it will be appreciated by those skilled in the art that the embodiments can be applied to other systems. In fact, systems for warpage compensation fall within the embodiments, as defined by the appended claims. The embodiments described above were chosen and described in order to best explain the principles of the embodiments and its practical applications. These embodiments were chosen to thereby enable others skilled in the art to best utilize the various embodiments with various modifications as are suited to the particular use contemplated.

It is to be understood that even though numerous characteristics and advantages of various embodiments have been set forth in the foregoing description, together with details of the structure and function of various embodiments, this disclosure is illustrative only. In some cases, certain subassemblies are only described in detail with one such embodiment. Nevertheless, it is recognized and intended that such subassemblies may be used in other embodiments. Changes may be made in detail, especially matters of structure and management of parts within the principles of the embodiments to the full extent indicated by the broad general meaning of the terms in which the appended claims are expressed.

Having disclosed exemplary embodiments and the best mode, modifications and variations may be made to the disclosed embodiments while remaining within the scope of the embodiments as defined by the following claims.

What is claimed is:

1. An apparatus comprising:

a substrate having a surface of a first coplanarity level and including a plurality of conductive bumps defining a second different virtual surface on the substrate, wherein a coplanarity level of the virtual surface is at most equal to a maximum coplanarity specification level to compensate for a warpage level of the substrate;

an adhesive conductive layer formed over the virtual surface of the plurality of conductive bumps; and

an OLED panel layer coupled to the substrate to connect an OLED electrode to electrode pads of the substrate via the adhesive conductive layer.

2. The apparatus of claim 1, wherein the maximum coplanarity specification level equals 30 micrometers per inch and a substrate warpage level of the substrate is within a range of 60 micrometers per inch through 700 micrometers per inch.

3. The apparatus of claim 1, wherein the selected substrate is comprised of a material selected from one of alumina ceramic, low-temperature co-fired ceramic, organic material and plastic material.

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4. The apparatus of claim 1, wherein the conductive bumps are comprised of one of a conductive metal and a conductive, plastic elastic material.

5. The apparatus of claim 1, wherein the conductive bumps are comprised of rubber.

6. The apparatus of claim 1, wherein the OLED panel layer further comprises:

a glass substrate;

an anode rail formed over an area of the glass substrate;

a diode formed over an area of the anode rail; and

a cathode rail formed over an area of the diode to contact to the substrate electrode pads via the conductive adhesive layer.

7. A system comprising:

an organic light emitting diode (OLED) display comprising a plurality of OLED display panel cells, each OLED display panel cell including a plurality of OLED display panel modules comprising:

a substrate including a plurality of conductive bumps having a virtual surface opposite the substrate and formed by applying a thermal process to the plurality of conductive bumps, wherein a coplanarity level of the virtual surface is at most equal to a coplanarity specification level to compensate for a warpage level of the substrate,

an adhesive conductive layer formed over the virtual surface of the plurality of conductive bumps, and

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an OLED panel layer coupled to the substrate to connect an OLED electrode to electrode pads contacting the substrate via the adhesive conductive layer; and

an OLED display panel drive to provide current to the plurality of OLED display panel cells to enable image display.

8. The system of claim 7, wherein the OLED layer comprises:

a glass substrate;

an anode rail formed over an area of the glass substrate;

a diode formed over an area of the anode rail; and

a cathode rail formed over an area of the diode to contact the substrate electrode pads via the conductive adhesive layer.

9. The system of claim 8, wherein the diode comprises one of a red light emitting diode (LED), a green LED and a blue LED.

10. The system of claim 7, wherein each OLED display panel cell comprises:

an OLED display panel module having a red OLED electrode;

an OLED display panel module having a blue OLED electrode; and

an OLED display panel module having a green OLED electrode.

* * * * *

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,798,137 B2
DATED : September 28, 2004
INVENTOR(S) : Ishida

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 1,

Line 46, delete "rumination" and insert -- lumination --.

Column 3,

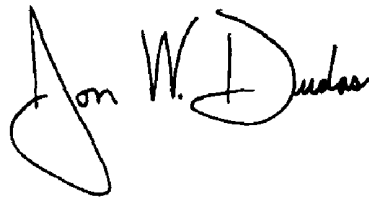
Line 60, delete "rumination" and insert -- lumination --.

Column 9,

Line 6, delete "planel" and insert -- panel --.

Signed and Sealed this

Seventeenth Day of May, 2005

A handwritten signature in black ink, reading "Jon W. Dudas". The signature is stylized, with a large, looped initial "J" and a distinct "D".

JON W. DUDAS
Director of the United States Patent and Trademark Office

专利名称(译)	用于显示面板基板组件的翘曲补偿的装置和方法		
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摘要(译)

描述了一种用于显示面板基板组件的翘曲补偿的装置和方法。描述了一种用于显示面板基板组件的翘曲补偿的方法和设备。在一个实施例中，该方法包括选择具有超过翘曲容差水平的衬底翘曲水平的衬底。一旦被选择，就在所选衬底的区域上形成多个导电凸块。一旦形成，就对多个导电凸块施加热处理以获得在所选衬底的区域上方的虚拟平面具有低于共面规格水平的共面性水平。这样，利用本发明的实施例，当利用本发明的实施例进行补偿时，可以利用具有不合标准翘曲水平的低成本衬底来形成OLED面板衬底组件。

